

Ultrafast Diode

50 A, 600 V

RURG5060

Description

The RURG5060 is an ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery ($t_{rr} = 75 \text{ ns}$ (@ $I_F = 50 \text{ A}$)
- Max Forward Voltage($V_F = 1.6 \text{ V}$ (@ $T_C = 25 \text{ }^\circ\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

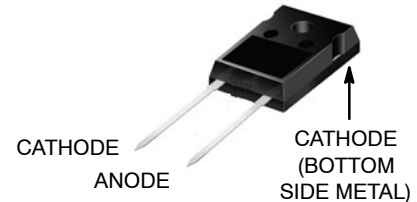
| Rating | Symbol | Value | Unit |
|---|----------------|-------------|------------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | 600 | V |
| Working Peak Reverse Voltage | V_{RWM} | 600 | V |
| DC Blocking Voltage | V_R | 600 | V |
| Average Rectified Forward Current ($T_C = 102 \text{ }^\circ\text{C}$) | $I_{F(AV)}$ | 50 | A |
| Repetitive Peak Surge Current (Square Wave, 20 kHz) | I_{FRM} | 100 | A |
| Nonrepetitive Peak Surge Current (Halfwave 1 Phase, 60 Hz) | I_{FSM} | 500 | A |
| Maximum Power Dissipation | P_D | 150 | W |
| Avalanche Energy (See Figure 7 and Figure 8) | E_{AVL} | 40 | mJ |
| Operating and Storage Temperature | T_{STG}, T_J | -65 to +175 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



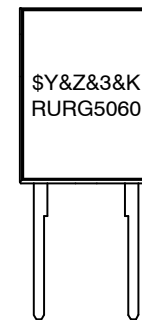
ON Semiconductor®

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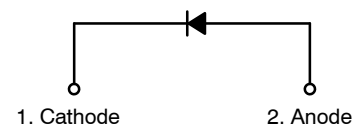


JEDEC STYLE 2 LEAD TO-247
340CL

MARKING DIAGRAM



\$Y = ON Semiconductor Logo
 &Z = Assembly Plant Code
 &3 = Numeric Date Code
 &K = Lot Code
 RURG5060 = Specific Device Code



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

RURG5060

PACKAGE MARKING AND ORDERING INFORMATION

| Part Number | Package | Brand |
|-------------|-----------|----------|
| RURG5060 | TO-247-2L | RURG5060 |

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|-----------------|---|---|-----|-----|-----|---------------------------|
| V_F | Instantaneous Forward Voltage (Pulse Width = 300 μs , Duty Cycle = 2%) | $I_F = 50\text{ A}$ | | | 1.6 | V |
| | | $I_F = 50\text{ A}$, $T_C = 150^\circ\text{C}$ | | | 1.4 | V |
| I_R | Instantaneous Reverse Current | $V_R = 600\text{ V}$ | | | 250 | μA |
| | | $V_R = 600\text{ V}$ $T_C = 150^\circ\text{C}$ | | | 1.5 | mA |
| T_{rr} | Reverse Recovery Time at $dI_F/dt = 100\text{ A}/\mu\text{s}$ (See Figure 6) Summation of $t_a + t_b$ | $I_F = 1\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$ | | | 65 | ns |
| | | $I_F = 50\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$ | | | 75 | ns |
| t_a | Time to Reach Peak Reverse Current at $dI_F/dt = 100\text{ A}/\mu\text{s}$ (See Figure 6) | $I_F = 50\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$ | | 30 | | ns |
| t_b | Time from Peak I_{RM} to Projected Zero Crossing of I_{RM} Based on a Straight Line from Peak I_{RM} Through 25% of I_{RM} (See Figure 6) | $I_F = 50\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$ | | 20 | | ns |
| $R_{\theta JC}$ | Thermal Resistance Junction to Case | | | | 1.0 | $^\circ\text{C}/\text{W}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CURVES

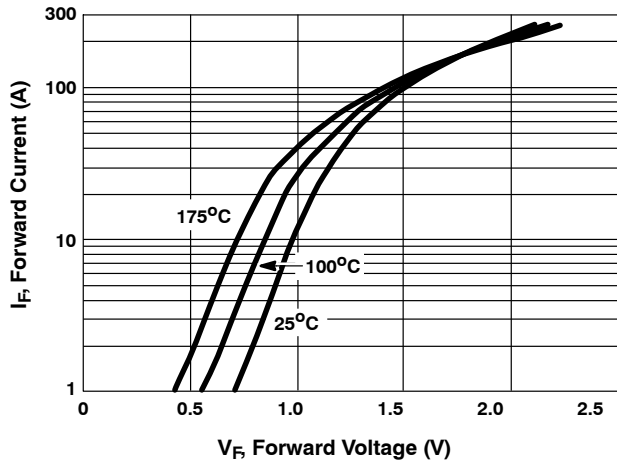


Figure 1. Forward Current vs. Forward Voltage

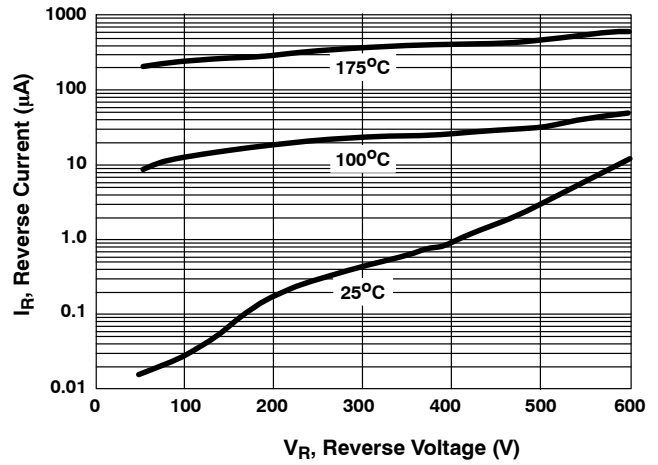


Figure 2. Reverse Current vs. Reverse Voltage

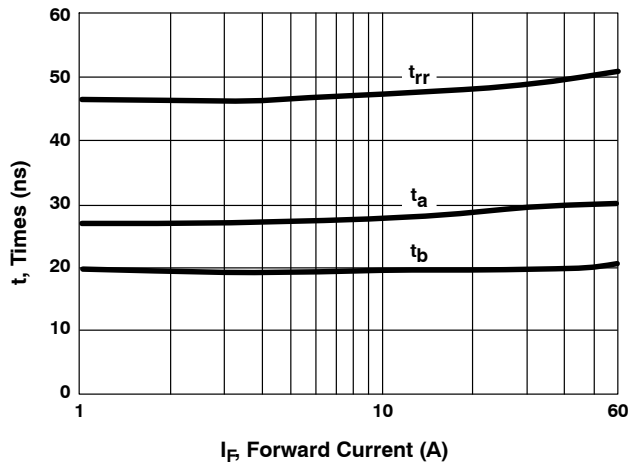


Figure 3. T_{rr} , t_a and t_b Curves vs. Forward Current

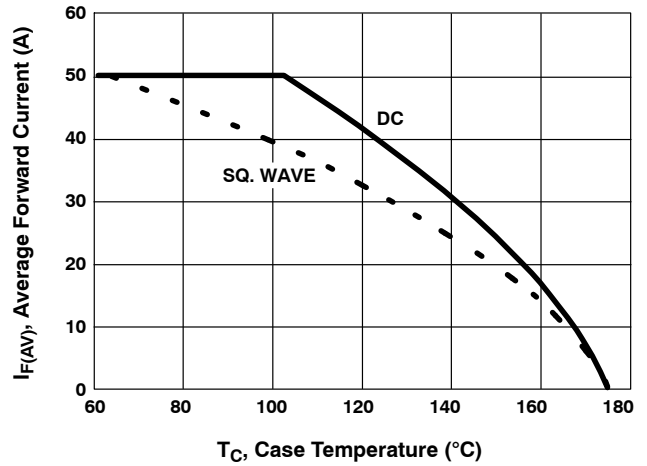


Figure 4. Current Derating Curve

TEST CIRCUITS AND WAVEFORMS

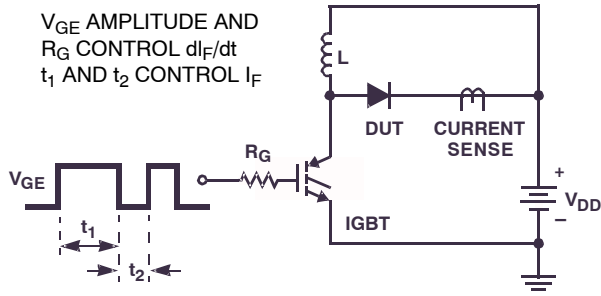


Figure 5. T_{rr} Test Circuit

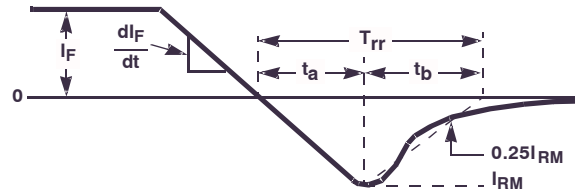


Figure 6. T_{rr} Waveforms and Definitions

$I = 1.4 \text{ A}$
 $L = 40 \text{ mH}$
 $R < 0.1 \Omega$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = \text{IGBT (} BV_{CES} > DUT V_{R(AVL)} \text{)}$

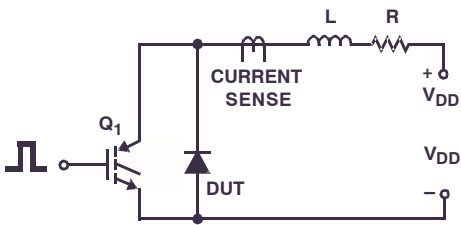


Figure 7. Avalanche Energy Test Circuit

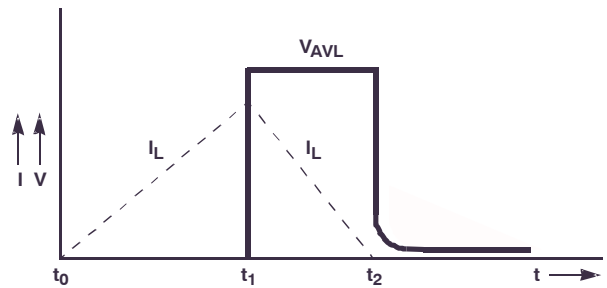


Figure 8. Avalanche Current and Voltage Waveforms

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

ON Semiconductor®



TO-247-2LD
CASE 340CL
ISSUE A

DATE 03 DEC 2019



⊕ 0.25 (M) B A (M)

NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
 A = Assembly Location
 Y = Year
 WW = Work Week
 ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DIM | MILLIMETERS | | |
|-----|-------------|-------|-------|
| | MIN | NOM | MAX |
| A | 4.58 | 4.70 | 4.82 |
| A1 | 2.29 | 2.40 | 2.66 |
| A2 | 1.30 | 1.50 | 1.70 |
| b | 1.17 | 1.26 | 1.35 |
| b2 | 1.53 | 1.65 | 1.77 |
| c | 0.51 | 0.61 | 0.71 |
| D | 20.32 | 20.57 | 20.82 |
| D1 | 16.37 | 16.57 | 16.77 |
| D2 | 0.51 | 0.93 | 1.35 |
| E | 15.37 | 15.62 | 15.87 |
| E1 | 12.81 | ~ | ~ |
| E2 | 4.96 | 5.08 | 5.20 |
| e | ~ | 11.12 | ~ |
| L | 15.75 | 16.00 | 16.25 |
| L1 | 3.69 | 3.81 | 3.93 |
| ∅P | 3.51 | 3.58 | 3.65 |
| ∅P1 | 6.61 | 6.73 | 6.85 |
| Q | 5.34 | 5.46 | 5.58 |
| S | 5.34 | 5.46 | 5.58 |

| | | |
|-------------------------|--------------------|--|
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